

# 64K (8K x 8) CMOS EPROM

# **FEATURES**

- · High speed performance
  - 120 ns access time available
- CMOS Technology for low power consumption
  - 20 mA Active current
  - 100 μA Standby current
- · Factory programming available
- · Auto-insertion-compatible plastic packages
- · Auto ID aids automated programming
- · Separate chip enable and output enable controls
- · High speed "express" programming algorithm
- Organized 8K x 8: JEDEC standard pinouts
  - 28-pin Dual-in-line package
  - 32-pin PLCC Package
  - 28-pin SOIC package
  - Tape and reel
- · Available for the following temperature ranges

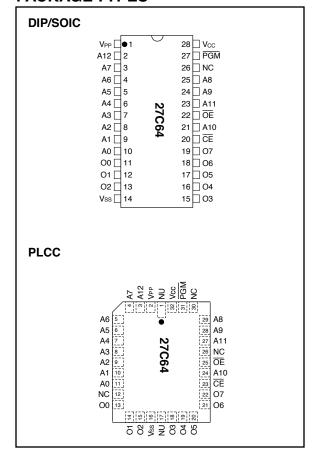
- Commercial: 0°C to +70°C - Industrial: -40°C to +85°C

# **DESCRIPTION**

The Microchip Technology Inc. 27C64 is a CMOS 64K bit (electrically) Programmable Read Only Memory. The device is organized as 8K words by 8 bits (8K bytes). Accessing individual bytes from an address transition or from power-up (chip enable pin going low) is accomplished in less than 120 ns. CMOS design and processing enables this part to be used in systems where reduced power consumption and high reliability are requirements.

A complete family of packages is offered to provide the most flexibility in applications. For surface mount applications, PLCC or SOIC packaging is available. Tape and reel packaging is also available for PLCC or SOIC packages.

# **PACKAGE TYPES**



# 1.0 ELECTRICAL CHARACTERISTICS

# 1.1 Maximum Ratings\*

Vcc and input voltages w.r.t. Vss.....-0.6V to + 7.25V

VPP voltage w.r.t. Vss during
programming .....-0.6V to +14V

Voltage on A9 w.r.t. Vss....-0.6V to +13.5V

Output voltage w.r.t. Vss...--0.6V to Vcc +1.0V

Storage temperature ...--65°C to +150°C

Ambient temp. with power applied ....-65°C to +125°C

\*Notice: Stresses above those listed under "Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operation listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

TABLE 1-1: PIN FUNCTION TABLE

Name	Function
A0-A12	Address Inputs
CE	Chip Enable
ŌĒ	Output Enable
PGM	Program Enable
VPP	Programming Voltage
O0 - O7	Data Output
Vcc	+5V Power Supply
Vss	Ground
NC	No Connection; No Internal Connections
NU	Not Used; No External Connection Is Allowed

TABLE 1-2: READ OPERATION DC CHARACTERISTICS

	$VCC = +5V (\pm 10\%)$ $Commercial: Tamb = 0^{\circ}C \text{ to } +70^{\circ}C$ $Industrial: Tamb = -40^{\circ}C \text{ to } +85^{\circ}C$								
Parameter	Part*	Status	Symbol	Min	Max	Units	Conditions		
Input Voltages	all	Logic "1" Logic "0"	VIH VIL	2.0 -0.5	Vcc+1 0.8	V V			
Input Leakage	all	1	ILI	-10	10	μΑ	VIN = 0 to VCC		
Output Voltages	all	Logic "1" Logic "0"	Voh Vol	2.4	0.45	V	IOH = -400 μA IOL = 2.1 mA		
Output Leakage	all	_	ILO	-10	10	μΑ	Vout = 0V to Vcc		
Input Capacitance	all	_	CIN	_	6	pF	VIN = 0V; Tamb = 25°C; f = 1 MHz		
Output Capacitance	all	_	Соит	_	12	pF	Vout = 0V; Tamb = 25°C; f = 1 MHz		
Power Supply Current, Active	C	TTL input TTL input	ICC1 ICC2		20 25	mA mA	VCC = 5.5V; VPP = VCC; f = 1 MHz; $\overline{OE} = \overline{CE} = V_{IL}$ ; IOUT = 0 mA; VIL = -0.1 to 0.8V; VIH = 2.0 to VCC; Note 1		
Power Supply Current, Standby	C I all	TTL input TTL input CMOS input	Icc(s) - -	_ _ _	2 3 100	mA mA μA	<u>CE</u> = Vcc ± 0.2V		
IPP Read Current VPP Read Voltage	all all	Read Mode Read Mode	IPP VPP	Vcc-0.7	100 Vcc	μA V	VPP = 5.5V		

<sup>\*</sup> Parts: C=Commercial Temperature Range; I =Industrial Temperature Range.

Note 1: Typical active current increases .5 mA per MHz up to operating frequency for all temperature ranges.

TABLE 1-3: READ OPERATION AC CHARACTERISTICS

AC Testing Waveform: VIH = 2.4V and VIL = 0.45V; VOH = 2.0V VOL = 0.8V

Output Load: 1 TTL Load + 100 pF

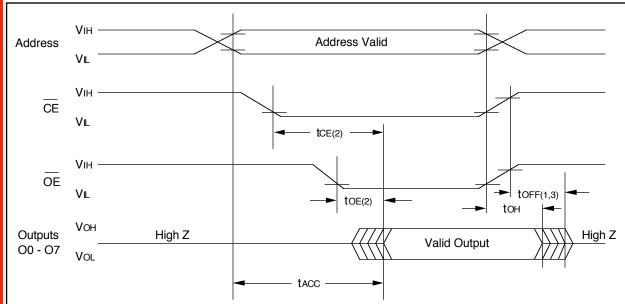
Input Rise and Fall Times: 10 ns

Ambient Temperature: Commercial: Tamb =  $0^{\circ}$ C to +70 $^{\circ}$ C Industrial: Tamb = -40 $^{\circ}$ C to +85 $^{\circ}$ C

27C64-12 27C64-15 27C64-17 27C64-20 27C64-25 **Parameter** Sym **Units Conditions** Min Max Min Max Min Max Min Max Min Max  $\overline{CE} = \overline{OE} = VIL$ Address to Output Delay **t**ACC 120 150 170 200 250 ns CE to Output Delay 120 150 170 200 250  $\overline{OE} = VIL$ **t**CE ns OE to Output Delay toe 65 70 70 75 100 ns  $\overline{CE} = VIL$  $\overline{\text{CE}}$  or  $\overline{\text{OE}}$  to O/P High 50 0 50 50 55 0 60 toff 0 0 0 ns Impedance Output Hold from toh 0 0 0 0 0 ns

# FIGURE 1-1: READ WAVEFORMS

Address CE or OE, whichever occurs first



Note 1: tOFF is specified for  $\overline{OE}$  or  $\overline{CE}$ , whichever occurs first.

2:  $\overline{OE}$  may be delayed up to tCE - tOE after the falling edge of  $\overline{CE}$  without impact on tCE.

3: This parameter is sampled and is not 100% tested.

TABLE 1-4: PROGRAMMING DC CHARACTERISTICS

	Ambient Temperature: Tamb = $25^{\circ}$ C $\pm 5^{\circ}$ C VCC = $6.5$ V $\pm 0.25$ V, VPP = VH = $13.0$ V $\pm 0.25$ V											
Parameter	Status	Status Symbol Min Max. Units Conditions										
Input Voltages	Logic"1" Logic"0"	VIH VIL	2.0 -0.1	VCC+1 0.8	V V							
Input Leakage	_	ILI	-10	10	μΑ	VIN = 0V to VCC						
Output Voltages	Logic"1" Logic"0"	Voh Vol	2.4 —	_ 0.45	V V	IOH = -400 μA IOL = 2.1 mA						
Vcc Current, program & verify	_	ICC2	_	20	mA	Note 1						
VPP Current, program	_	IPP2	_	25	mA	Note 1						
A9 Product Identification	_	Vн	11.5	12.5	٧							

Note 1: Vcc must be applied simultaneously or before VPP and removed simultaneously or after VPP.

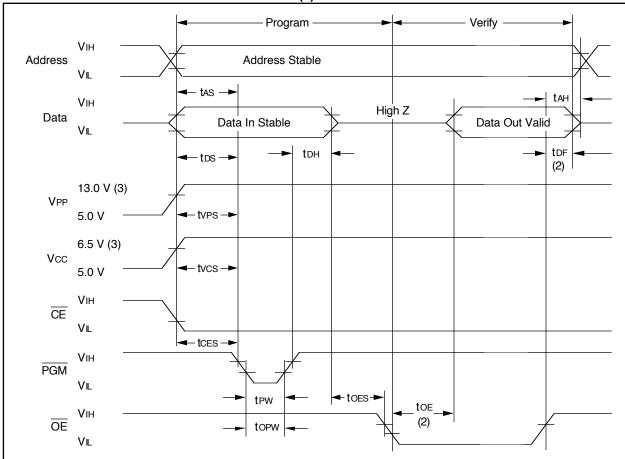
# TABLE 1-5: PROGRAMMING AC CHARACTERISTICS

for Program, Program Verify and Program Inhibit Modes AC Testing Waveform: VIH=2.4V and VIL=0.45V; VOH=2.0V; VOL=0.8V Ambient Temperature: Tamb=25°C $\pm$ 5°C VCC= 6.5V $\pm$ 0.25V, VPP = VH = 13.0V $\pm$ 0.25V									
Parameter	Symbol	Min	Max	Units	Remarks				
Address Set-Up Time	tas	2	_	μS					
Data Set-Up Time	tos	2	_	μS					
Data Hold Time	tDH	2	_	μS					
Address Hold Time	tah	0	_	μS					
Float Delay (2)	tDF	0	130	ns					
Vcc Set-Up Time	tvcs	2	_	μS					
Program Pulse Width (1)	tpw	95	105	μS	100 μs typical				
CE Set-Up Time	tces	2	_	μS					
OE Set-Up Time	toes	2	_	μS					
VPP Set-Up Time	tvps	2	_	μS					
Data Valid from OE	toe	_	100	ns					

Note 1: For express algorithm, initial programming width tolerance is 100  $\mu s$  ±5%.

<sup>2:</sup> This parameter is only sampled and not 100% tested. Output float is defined as the point where data is no longer driven (see timing diagram).

FIGURE 1-2: PROGRAMMING WAVEFORMS (1)



Notes: (1) The input timing reference is 0.8 V for VIL and 2.0 V for VIH.

- (2) tDF and tOE are characteristics of the device but must be accommodated by the programmer.
- (3)  $Vcc = 6.5 \text{ V} \pm 0.25 \text{ V}$ ,  $VPP = VH = 13.0 \text{ V} \pm 0.25 \text{ V}$  for Express algorithm.

TABLE 1-6: MODES

Operation Mode	CE	ŌĒ	PGM	<b>V</b> PP	<b>A</b> 9	00 - 07	
Read	VIL	VIL	VIH	Vcc	Х	Dout	
Program	VIL	VIH	VIL	Vн	Х	DIN	
Program Verify	VIL	VIL	VIH	Vн	Х	Dout	
Program Inhibit	VIH	Х	X	Vн	Х	High Z	
Standby	VIH	Х	X	Vcc	Х	High Z	
Output Disable	VIL	VIH	VIH	Vcc	Х	High Z	
Identity	VIL	VIL	VIH	Vcc	Vн	Identity Code	



# 1.2 Read Mode

(See Timing Diagrams and AC Characteristics)

Read Mode is accessed when

- a) the  $\overline{\text{CE}}$  pin is low to power up (enable) the chip
- b) the  $\overline{\text{OE}}$  pin is low to gate the data to the output pins

For Read operations, if the addresses are stable, the address access time (tACC) is equal to the delay from  $\overline{\text{CE}}$  to output (tCE). Data is transferred to the output after a delay from the falling edge of  $\overline{\text{OE}}$  (tOE).

# 1.3 Standby Mode

The standby mode is defined when the  $\overline{CE}$  pin is high (VIH) and a program mode is not defined.

When these conditions are met, the supply current will drop from 20 mA to 100  $\mu$ A.

## 1.4 Output Enable

This feature eliminates bus contention in microprocessor-based systems in which multiple devices may drive the bus. The outputs go into a high impedance state when the following condition is true:

• The  $\overline{\text{OE}}$  and  $\overline{\text{PGM}}$  pins are both high.

# 1.5 <u>Erase Mode (U.V. Windowed</u> <u>Versions)</u>

Windowed products offer the capability to erase the memory array. The memory matrix is erased to the all 1's state when exposed to ultraviolet light. To ensure complete erasure, a dose of 15 watt-second/cm² is required. This means that the device window must be placed within one inch and directly underneath an ultraviolet lamp with a wavelength of 2537 Angstroms, intensity of  $12,000\mu\text{W/cm}^2$  for approximately 20 minutes.

# 1.6 **Programming Mode**

The Express Algorithm has been developed to improve the programming throughput times in a production environment. Up to ten 100-microsecond pulses are applied until the byte is verified. No overprogramming is required. A flowchart of the express algorithm is shown in Figure 1-3.

Programming takes place when:

- a) Vcc is brought to the proper voltage,
- b) VPP is brought to the proper VH level,
- c) the  $\overline{CE}$  pin is low,
- d) the  $\overline{OE}$  pin is high, and
- e) the  $\overline{PGM}$  pin is low.

Since the erased state is "1" in the array, programming of "0" is required. The address to be programmed is set via pins A0-A12 and the data to be programmed is presented to pins O0-O7. When data and address are stable,  $\overline{\text{OE}}$  is high,  $\overline{\text{CE}}$  is low and a low-going pulse on the  $\overline{\text{PGM}}$  line programs that location.

# 1.7 <u>Verify</u>

After the array has been programmed it must be verified to ensure all the bits have been correctly programmed. This mode is entered when all the following conditions are met:

- a) Vcc is at the proper level,
- b) VPP is at the proper VH level,
- c) the  $\overline{CE}$  line is low,
- d) the PGM line is high, and
- e) the OE line is low.

#### 1.8 Inhibit

When programming multiple devices in parallel with different data, only  $\overline{\text{CE}}$  or  $\overline{\text{PGM}}$  need be under separate control to each device. By pulsing the  $\overline{\text{CE}}$  or  $\overline{\text{PGM}}$  line low on a particular device in conjunction with the  $\overline{\text{PGM}}$  or  $\overline{\text{CE}}$  line low, that device will be programmed; all other devices with  $\overline{\text{CE}}$  or  $\overline{\text{PGM}}$  held high will not be programmed with the data, although address and data will be available on their input pins (i.e., when a high level is present on  $\overline{\text{CE}}$  or  $\overline{\text{PGM}}$ ); and the device is inhibited from programming.

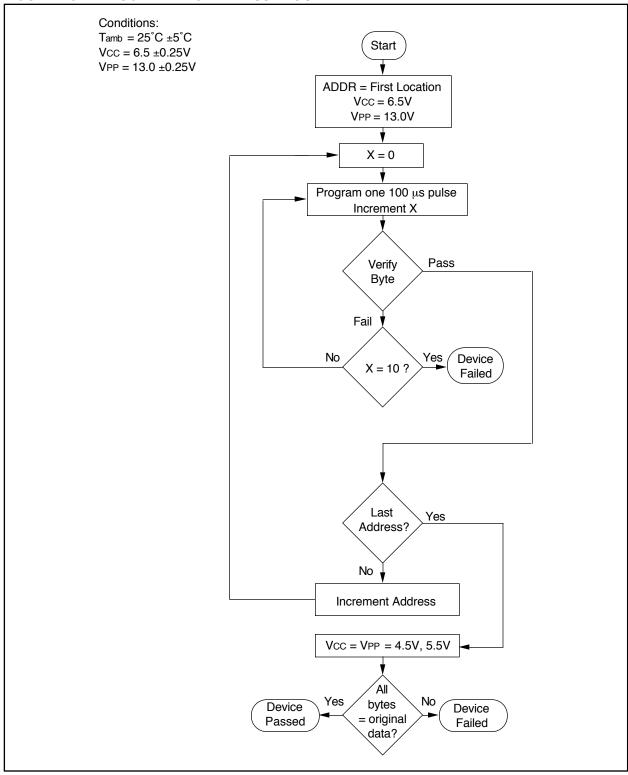
## 1.9 Identity Mode

In this mode, specific data is output which identifies the manufacturer as Microchip Technology Inc. and device type. This mode is entered when Pin A9 is taken to VH (11.5V to 12.5V). The  $\overline{\text{CE}}$  and  $\overline{\text{OE}}$  lines must be at VIL. A0 is used to access any of the two non-erasable bytes whose data appears on O0 through O7.

Pin →	Input	Output								
Identity	Α0	0 7	O 6	O 5	O 4	O 3	O 2	0	0	H e x
Manufacturer Device Type*	VIL VIH	0 0	0 0	1	0	1	0 0	0	1	29 02

<sup>\*</sup> Code subject to change

FIGURE 1-3: PROGRAMMING EXPRESS ALGORITHM



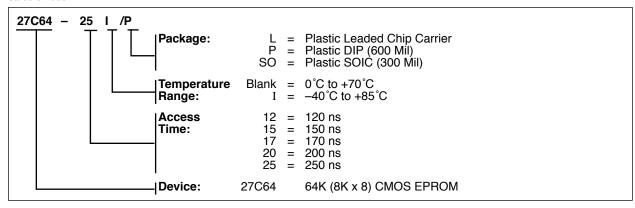
**NOTES:** 

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# **27C64 Product Identification System**

To order or to obtain information, e.g., on pricing or delivery, please use the listed part numbers, and refer to the factory or the listed sales offices.



# WORLDWIDE SALES & SERVICE

#### **AMERICAS**

#### **Corporate Office**

Microchip Technology Inc. 2355 West Chandler Blvd. Chandler, AZ 85224-6199 Tel: 602 786-7200 Fax: 602 786-7277 Technical Support: 602 786-7627 Web: http://www.microchip.com

#### **Atlanta**

Microchip Technology Inc. 500 Sugar Mill Road, Suite 200B Atlanta, GA 30350

Tel: 770 640-0034 Fax: 770 640-0307

#### **Boston**

Microchip Technology Inc. 5 Mount Royal Avenue Marlborough, MA 01752

Tel: 508 480-9990 Fax: 508 480-8575

## Chicago

Microchip Technology Inc. 333 Pierce Road, Suite 180 Itasca, IL 60143

Tel: 708 285-0071 Fax: 708 285-0075

#### **Dallas**

Microchip Technology Inc. 14651 Dallas Parkway, Suite 816 Dallas, TX 75240-8809 Tel: 972 991-7177 Fax: 972 991-8588

#### Dayton

Microchip Technology Inc. Suite 150 Two Prestige Place Miamisburg, OH 45342 Tel: 513 291-1654 Fax: 513 291-9175

# Los Angeles

Microchip Technology Inc. 18201 Von Karman, Suite 1090 Irvine, CA 92612

Tel: 714 263-1888 Fax: 714 263-1338

#### **New York**

Microchip Technmgy Inc. 150 Motor Parkway, Suite 416 Hauppauge, NY 11788

Tel: 516 273-5305 Fax: 516 273-5335

#### San Jose

Microchip Technology Inc. 2107 North First Street, Suite 590 San Jose, CA 95131 Tel: 408 436-7950 Fax: 408 436-7955

**Toronto** 

Microchip Technology Inc. 5925 Airport Road, Suite 200 Mississauga, Ontario L4V 1W1, Canada Tel: 905 405-6279 Fax: 905 405-6253

#### ASIA/PACIFIC

Microchip Technology Unit 406 of Shanghai Golden Bridge Bldg. 2077 Yan'an Road West, Hongiao District Shanghai, Peoples Republic of China Tel: 86 21 6275 5700

Fax: 011 86 21 6275 5060

### **Hong Kong**

Microchip Technology RM 3801B, Tower Two Metroplaza 223 Hing Fong Road Kwai Fong, N.T. Hong Kong Tel: 852 2 401 1200 Fax: 852 2 401 3431

India

Microchip Technology No. 6, Legacy, Convent Road Bangalore 560 025 India Tel: 91 80 526 3148 Fax: 91 80 559 9840

#### Korea

Microchip Technology 168-1, Youngbo Bldg. 3 Floor Samsung-Dong, Kangnam-Ku, Seoul, Korea

Tel: 82 2 554 7200 Fax: 82 2 558 5934

#### Singapore

Microchip Technology 200 Middle Road #10-03 Prime Centre Singapore 188980

Tel: 65 334 8870 Fax: 65 334 8850

### Taiwan, R.O.C

Microchip Technology 10F-1C 207 Tung Hua North Road Taipei, Taiwan, ROC

Tel: 886 2 717 7175 Fax: 886 2 545 0139

## **EUROPE**

#### United Kingdom

Arizona Microchip Technology Ltd. Unit 6, The Courtyard Meadow Bank, Furlong Road Bourne End, Buckinghamshire SL8 5AJ Tel: 44 1628 850303 Fax: 44 1628 850178

#### France

Arizona Microchip Technology SARL Zone Industrielle de la Bonde 2 Rue du Buisson aux Fraises 91300 Massy - France Tel: 33 1 69 53 63 20 Fax: 33 1 69 30 90 79

### Germany

Arizona Microchip Technology GmbH Gustav-Heinemann-Ring 125 D-81739 Muenchen, Germany

Tel: 49 89 627 144 0 Fax: 49 89 627 144 44

Arizona Microchip Technology SRL Centro Direzionale Colleone Pas Taurus 1 Viale Colleoni 1

20041 Agrate Brianza Milan Italy

Tel: 39 39 6899939 Fax: 39 39 689 9883

Microchip Technology Intl. Inc. Benex S-1 6F 3-18-20, Shin Yokohama Kohoku-Ku, Yokohama Kanagawa 222 Japan

Tel: 81 45 471 6166 Fax: 81 45 471 6122

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